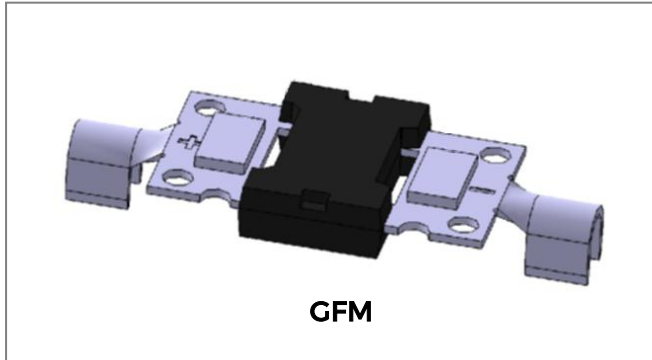


## GF5145TC Power Schottky Module Bypass Diode



### Features

- Trench MOS Schottky technolog
- Low thermal resistance
- Lower forward voltage drop, low power loss
- Isolate Package design, ideal for heat dispersion
- High forward current capability
- Excellent anti-humidity
- Low profile package
- High forward surge capability
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request

### Mechanical Data

- Case: GFM
- Terminals: Copper
- High temperature soldering guaranteed
- Heated-tool welding 260°C, 10seconds
- Marking Code: GF5145TC

### Maximum Ratings (limiting values, at 25 °C unless otherwise specified)

| Characteristics  | Symbol                          | Condition                       | Max. | Units |
|--|---------------------------------|---------------------------------|------|-------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage | $V_{RRM}$<br>$V_{RWM}$<br>$V_R$ | -                               | 45   | V     |
| Average Rectified Forward Current  | $I_{F(AV)}$                     | $T_C=111^\circ\text{C}$ , In DC | 50   | A     |
| Peak One Cycle Non-Repetitive Surge Current  | $I_{FSM}$                       | 8.3 ms, half Sine pulse         | 450  | A     |

### Electrical Characteristics:

| Characteristics       | Symbol   | Condition   | Typ. | Max. | Units |
|-----------------------|----------|---|------|------|-------|
| Forward Voltage Drop* | $V_{F1}$ | @ 50A, Pulse, $T_J = 25^\circ\text{C}$                | 0.47 | 0.52 | V     |
| Reverse Current*      | $I_{R1}$ | @ $V_R = \text{rated } V_R$ $T_J = 25^\circ\text{C}$  | 0.03 | 0.5  | mA    |
|                       | $I_{R1}$ | @ $V_R = \text{rated } V_R$ $T_J = 100^\circ\text{C}$ | -    | 30   | mA    |
|                       | $I_{R1}$ | @ $V_R = \text{rated } V_R$ $T_J = 125^\circ\text{C}$ | 30   | 80   | mA    |

\* Pulse width < 300  $\mu\text{s}$ , duty cycle < 2%

**Thermal-Mechanical Specifications:**

| Characteristics                             | Symbol                | Condition  | Specification | Units                       |
|---|-----------------------|--|---------------|-----------------------------|
| Junction Temperature                        | $T_J$                 | IN DC Forward Mode, without reverse bias, $t \leq 1$ h | -55 to +200   | $^{\circ}\text{C}$          |
| Storage Temperature                         | $T_{\text{stg}}$      | -  | -55 to +150   | $^{\circ}\text{C}$          |
| Typical Thermal Resistance Junction to Case | $R_{\theta\text{JC}}$ | -  | 1.5           | $^{\circ}\text{C}/\text{W}$ |

**Ratings and Characteristics Curve**

Figure1 Typical Forward Characteristics

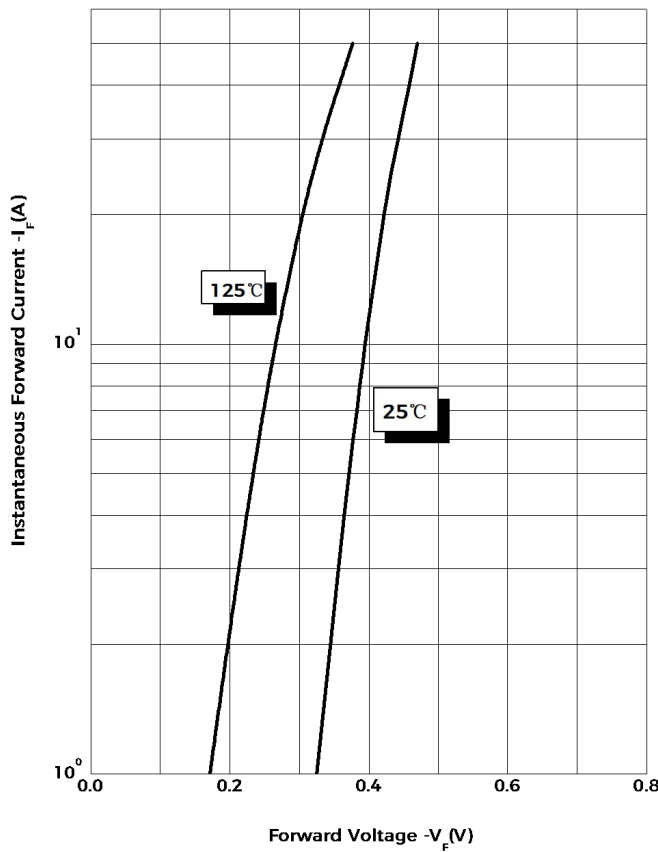


Figure 2 Typical Reverse Characteristics

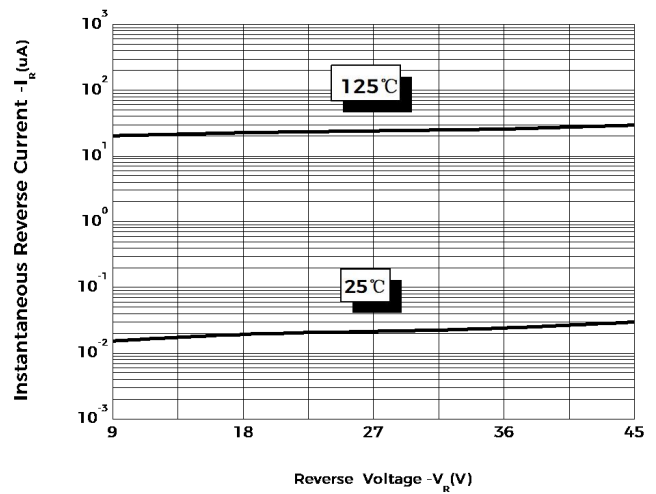
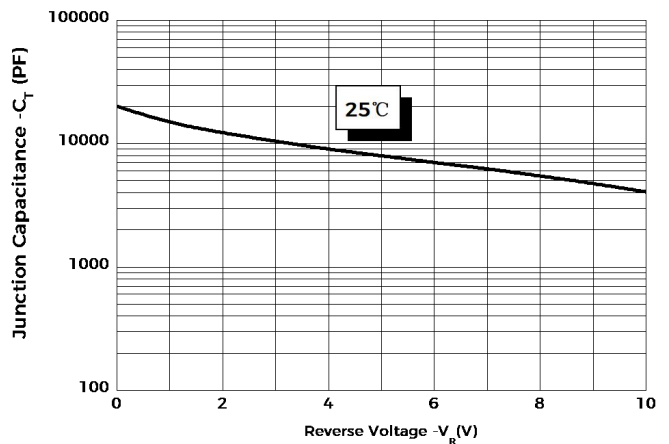


Figure 3 Typical Junction Capacitance

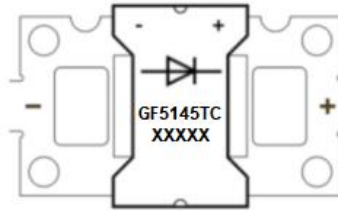


Technical Data  
Data Sheet N3051, Rev.-

**Ordering Information**

| Device   | Package | Shipping     |
|----------|---------|--------------|
| GF5145TC | GFM     | 30pcs / Tube |

**Marking Diagram**

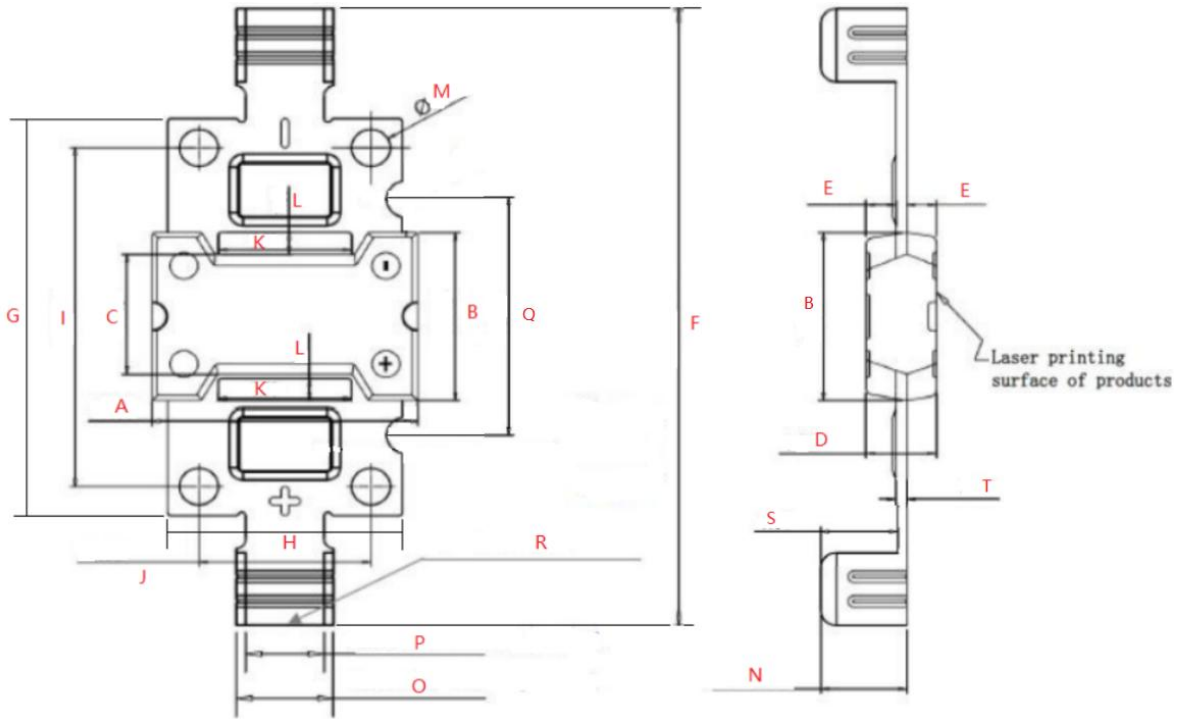


Where XXXXX is YYWWL

GF5145TC = Marking Code  
YY = Year  
WW = Week  
L = Lot Number

| Order P/N   | Terminals  | Additional   |
|-------------|------------|--------------|
| GF5145TC-S1 | Tin Plated | None         |
| GF5145TC-S3 | Tin Plated | Solder Block |

**Mechanical Dimensions GFM (Millimeters)**



| Symbol | Dimensions in millimeters |         |       |
|--------|---------------------------|---------|-------|
|        | Min.                      | Typical | Max   |
| A      | 16.90                     | 17.00   | 17.10 |
| B      | 11.38                     | 11.48   | 11.58 |
| C      | 8.15                      | 8.20    | 8.25  |
| D      | 4.40                      | 4.50    | 4.60  |
| E      | 1.85                      | 1.90    | 1.95  |
| F      | 41.90                     | 42.00   | 42.10 |
| G      | 26.90                     | 27.00   | 27.10 |
| H      | 14.90                     | 15.00   | 15.60 |
| I      | 22.90                     | 23.00   | 23.10 |
| J      | 10.90                     | 11.00   | 11.10 |
| K      | -                         | 8.50    | -     |
| L      | -                         | 1.50    | -     |
| M      | -                         | ∅2.50   | 2.55  |
| N      | 5.35                      | 5.50    | 5.65  |
| O      | 6.20                      | 6.30    | 6.40  |
| P      | 4.90                      | 5.00    | 5.10  |
| Q      | 15.95                     | 16.00   | 16.05 |
| R      | 2.80                      | 2.90    | 3.00  |
| S      | 4.75                      | 4.80    | 4.85  |
| T      | 0.67                      | 0.70    | 0.73  |

Dimension H includes Burrs/cutting residuals.

**Technical Data**  
**Data Sheet N3051, Rev.-**

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